

Supplementary Materials

Effects of Annealing Conditions on Mixed Lead Halide Perovskite Solar Cells and Their Thermal Stability Investigation

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Figure S1. AFM phase images of MA0.7FA0.3Pb(I0.9Br0.1)3 perovskite films annealed at 100 °C for 10 (**a**), 20 (**b**), 30 (**c**) and 40 (**d**) min.





Figure S2. SEM images and grain size distribution histograms of MA_{0.7}FA_{0.3}Pb(I_{0.9}Br_{0.1})₃ perovskite films annealed at 100 °C for 10 (**a**), 20 (**b**), 30 (**c**) and 40 (**d**) minutes. Image size was 2.2 μm × 2.2 μm. (The grain size was collected by software "Nano Measurer".)

Table S1. Photovoltaic parameters of MA0.7FA0.3Pb(I0.9Br0.1)₃ perovskite solar cells annealed at 90 $^{\circ}$ C,100 $^{\circ}$ C and 110 $^{\circ}$ C for 30 min.^a

Annealing Temperature (°C)	Jsc (mA/cm²)	<i>V</i> oc (V)	FF (%)	PCE (%)
90	17.01 ± 0.38	0.96 ± 0.10	77.88 ± 4.42	12.74 ± 0.93
100	19.65 ± 0.46	0.98 ± 0.09	82.43 ± 3.26	15.81 ± 0.58
110	16.97 ± 0.74	1.02 ± 0.14	73.03 ± 5.41	12.59 ± 1.11

^a Each value is derived from 5 cells made from the same batch.

(a) $\begin{array}{c} (a) \\ (b) \\ (b) \\ (c) \\$

J_{SC} (mA/cm²) (d) (c) Count Count Count 0.8 0.90 0.92 VOC (V) 58 60 62 64 0.94 52 56 0.88 0.96 FF (%)

Figure S3. Statistics of PCE (**a**), J_{SC} (**b**), V_{OC} (**c**) and FF (**d**) distribution of 10 flexible devices based on 10 devices from the same batch.